

TLV5630, TLV5631, TLV5632 8-CHANNEL, 12-/10-/8-BIT, 2.7-V TO 5.5-V LOW POWER DIGITAL-TO-ANALOG CONVERTERS WITH POWER DOWN AND INTERNAL REFERENCE

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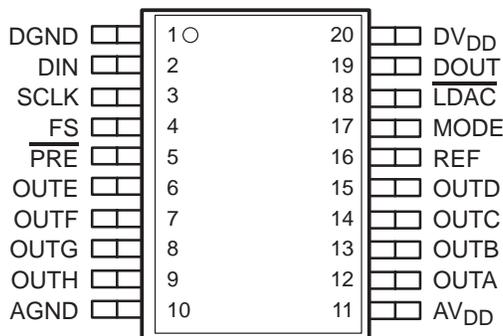
features

- Eight Voltage Output DACs in One Package
 - TLV5630 . . . 12-Bit
 - TLV5631 . . . 10-Bit
 - TLV5632 . . . 8-Bit
- Programmable Settling Time vs Power Consumption
 - 1 μ s in Fast Mode
 - 3 μ s in Slow Mode
- Compatible With TMS320 and SPI Serial Ports
- Monotonic Over Temperature
- Low Power Consumption:
 - 18 mW in Slow Mode at 3 V
 - 48 mW in Fast Mode at 3 V
- Power Down Mode
- Internal Reference
- Data Output for Daisy Chaining

applications

- Digital Servo Control Loops
- Digital Offset and Gain Adjustment
- Industrial Process Control
- Machine and Motion Control Devices
- Mass Storage Devices

DW OR PW PACKAGE
(TOP VIEW)



description

The TLV5630, TLV5631, and TLV5632 are pin compatible eight channel 12-/10-/8-bit voltage output DACs each with a flexible serial interface. The serial interface allows glueless interface to TMS320 and SPI, QSPI, and Microwire serial ports. It is programmed with a 16-bit serial string containing 4 control and 12 data bits.

Additional features are a power down mode, an $\overline{\text{LDAC}}$ input for simultaneous update of all eight DAC outputs, and a data output which can be used to cascade multiple devices and an internal programmable band-gap reference.

The resistor string output voltage is buffered by a rail-to-rail output amplifier with a programmable settling time to allow the designer to optimize speed vs power dissipation. The buffered, high-impedance reference input can be connected to the supply voltage.

Implemented with a CMOS process, the DACs are designed for single supply operation from 2.7 V to 5.5 V. The devices are available in 20 pin SOIC and TSSOP packages.

AVAILABLE OPTIONS

T _A	PACKAGE		
	SOIC (DW)	TSSOP (PW)	RESOLUTION
–40°C to 85°C	TLV5630IDW	TLV5630IPW	12
	TLV5631IDW	TLV5631IPW	10
	TLV5632IDW	TLV5632IPW	8



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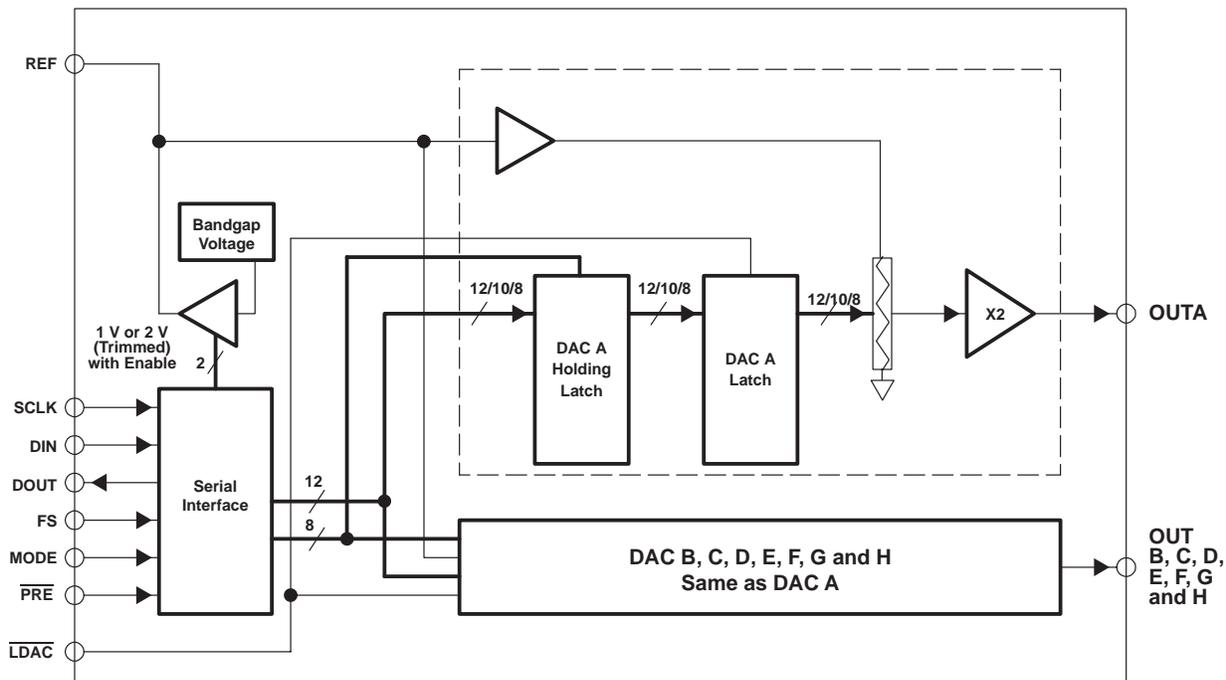
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functional block diagram



Terminal Functions

TERMINAL NAME	NO.	I/O	DESCRIPTION
AGND	10	P	Analog ground
AV _{DD}	11	P	Analog power supply
DGND	1	P	Digital ground
DIN	2	I	Digital serial data input
DOUT	19	O	Digital serial data output
DV _{DD}	20	P	Digital power supply
FS	4	I	Frame sync input
LDAC	18	I	Load DAC. The DAC outputs are only updated, if this signal is low. It is an asynchronous input.
MODE	17	I	DSP/μC mode pin. High = μC mode, NC = DSP mode.
PRE	5	I	Preset input
REF	16	I/O	Voltage reference input/output
SCLK	3	I	Serial clock input
OUTA–OUTH	12–15, 6–9	O	DAC outputs A, B, C, D, E, F, G and H

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absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Supply voltage, (AV _{DD} , DV _{DD} to GND)	7 V
Reference input voltage range	– 0.3 V to AV _{DD} + 0.3
Digital input voltage range	– 0.3 V to DV _{DD} + 0.3
Operating free-air temperature range, T _A	–40°C to 85°C
Storage temperature range, T _{stg}	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

		MIN	TYP	MAX	UNIT
Supply voltage, AV _{DD} , DV _{DD}	5-V operation	4.5	5	5.5	V
	3-V operation	2.7	3	3.3	V
High level digital input, V _{IH}	DV _{DD} = 2.7 V to 5.5 V	2			V
Low level digital input, V _{IL}	DV _{DD} = 2.7 V to 5.5 V			0.8	V
Reference voltage, V _{ref}	AV _{DD} = 5 V	GND	2.048	AV _{DD}	V
	AV _{DD} = 3 V	GND	1.024	AV _{DD}	
Analog output load resistance, R _L		2			kΩ
Analog output load capacitance, C _L				100	pF
Clock frequency, f _{CLK}				30	MHz
Operating free-air temperature, T _A		–40		85	°C

electrical characteristics over recommended operating conditions (unless otherwise noted)

power supply

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
I _{DD}	Power supply current	No load, All inputs = DV _{DD} or GND	V _{ref} = 2.048 V,	Fast	16	21	mA
				Slow	6	8	
	Power-down supply current				0.1		μA
POR	Power on threshold				2		V
PSRR	Power supply rejection ratio	Full scale, See Note 1			–50		dB

NOTES: 1. Power supply rejection ratio at full scale is measured by varying AV_{DD} and is given by:

$$PSRR = 20 \log [(E_G(AV_{DDmax}) - E_G(AV_{DDmin})) / V_{DDmax}]$$



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electrical characteristics over recommended operating conditions (unless otherwise noted)
(continued)

static DAC specifications

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
Resolution	TLV5630				12		Bits
	TLV5631				10		Bits
	TLV5632				8		Bits
INL Integral nonlinearity	TLV5630	$V_{ref} = 1\text{ V}, 2\text{ V}$	Code 40 to 4095		± 2	± 6	LSB
	TLV5631		Code 20 to 1023		± 0.5	± 2	LSB
	TLV5632		Code 6 to 255		± 0.3	± 1	LSB
DNL Differential nonlinearity	TLV5630	$V_{ref} = 1\text{ V}, 2\text{ V}$	Code 40 to 4095		± 0.5	± 1	LSB
	TLV5631		Code 20 to 1023		± 0.1	± 1	LSB
	TLV5632		Code 6 to 255		± 0.1	± 1	LSB
EZS Zero scale error (offset error at zero scale)					± 30	mV	
EZS TC Zero scale error temperature coefficient					30	$\mu\text{V}/^\circ\text{C}$	
EG Gain error					± 0.6	%Full Scale V	
EGTC Gain error temperature coefficient					10	ppm/ $^\circ\text{C}$	

output specifications

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_O Voltage output range		$R_L = 10\text{ k}\Omega$	0	$AV_{DD}-0.4$		V
Output load regulation accuracy		$R_L = 2\text{ k}\Omega$ vs $10\text{ k}\Omega$			± 0.3	%Full Scale V

reference output

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{REFOUTL}$ Low reference voltage			1.010	1.024	1.040	V
$V_{REFOUTH}$ High reference voltage		$V_{DD} > 4.75\text{ V}$	2.020	2.048	2.096	V
$I_{ref}(\text{Source})$ Output source current					1	mA
$I_{ref}(\text{Sink})$ Output sink current			-1			mA
Load capacitance		See Note 2	1	10		μF
PSRR Power supply rejection ratio				60		dB

NOTE 2: In parallel with a 100 nF capacitor

reference input

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_I Input voltage range				0		AV_{DD}	V
R_I Input resistance					50		k Ω
C_i Input capacitance					10		pF
Reference input bandwidth	$V_{ref} = 0.4 V_{pp} + 2.048\text{ Vdc}$, Input code = 0x800	Fast			2.2		MHz
		Slow			1.9		MHz
Reference feedthrough	$V_{ref} = 2 V_{pp}$ at 1 kHz + 2.048 Vdc (see Note 3)				-84		dB

NOTE 3: Reference feedthrough is measured at the DAC output with an input code = 0x000.



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electrical characteristics over recommended operating conditions (unless otherwise noted)
(continued)

digital inputs

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{IH}	High-level digital input current	$V_I = DV_{DD}$			1	μA
I_{IL}	Low-level digital input current	$V_I = 0 V$	-1			μA
C_I	Input capacitance			8		pF

digital output

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{OH}	High-level digital output voltage	$R_L = 10 k\Omega$	2.6			V
V_{OL}	Low-level digital output voltage	$R_L = 10 k\Omega$			0.4	V
	Output voltage rise time	$R_L = 10 k\Omega, C_L = 20 pF$, Includes propagation delay		5	10	ns

analog output dynamic performance

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
$t_{s(FS)}$	Output settling time, full scale	$R_L = 10 k\Omega$	$C_L = 100 pF$, See Note 4	Fast	1	3	μs
				Slow	3	7	
$t_{s(CC)}$	Output settling time, code to code	$R_L = 10 k\Omega$	$C_L = 100 pF$, See Note 5	Fast	0.5	1	μs
				Slow	1	2	
SR	Slew rate	$R_L = 10 k\Omega$	$C_L = 100 pF$, See Note 6	Fast	4	10	V/ μs
				Slow	1	3	
	Glitch energy	See Note 7			4		nV-s
	Channel crosstalk	10 kHz sine, 4 V _{pp}			-90		dB

- NOTES: 4. Settling time is the time for the output signal to remain within ± 0.5 LSB of the final measured value for a digital input code change of 0x080 to 0xFFFF and 0xFFFF to 0x080 respectively. Assured by design; not tested.
5. Settling time is the time for the output signal to remain within ± 0.5 LSB of the final measured value for a digital input code change of one count. The max time applies to code changes near zero scale or full scale. Assured by design; not tested.
6. Slew rate determines the time it takes for a change of the DAC output from 10% to 90% full scale voltage.
7. Code transition: TLV5630 – 0x7FF to 0x800, TLV5631 – 0x7FC to 0x800, TLV5632 – 0x7F0 to 0x800.

digital input timing requirements

PARAMETER		MIN	TYP	MAX	UNIT
$t_{su(FS-CK)}$	Setup time, FS low before first negative SCLK edge	8			ns
$t_{su(C16-FS)}$	Setup time, 16 th negative edge after FS low on which bit D0 is sampled before rising edge of FS. μC mode only	10			ns
$t_{wL(LDAC)}$	LDAC duration low	10			ns
t_{wH}	SCLK pulse duration high	16			ns
t_{wL}	SCLK pulse duration low	16			
$t_{su(D)}$	Setup time, data ready before SCLK falling edge	8			ns
$t_{h(D)}$	Hold time, data held valid after SCLK falling edge	5			ns
$t_{wH(FS)}$	FS duration high	10			ns
$t_{wL(FS)}$	FS duration low	10			ns
t_s	Settling time	See AC specs			



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TYPICAL CHARACTERISTICS

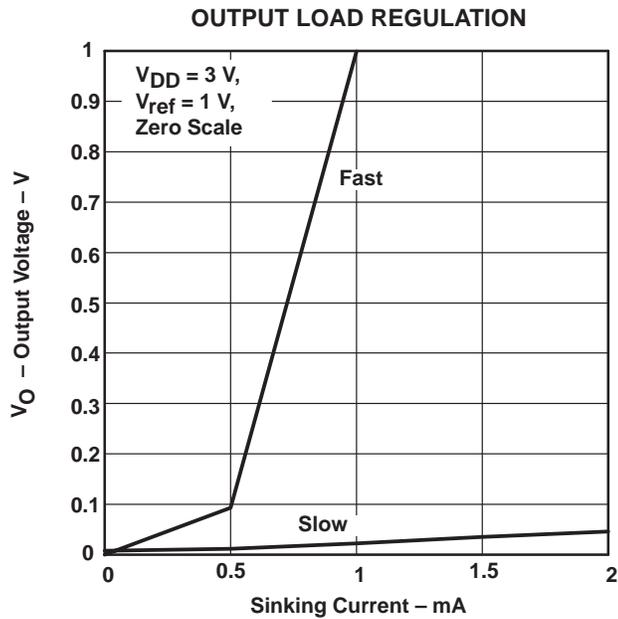


Figure 1

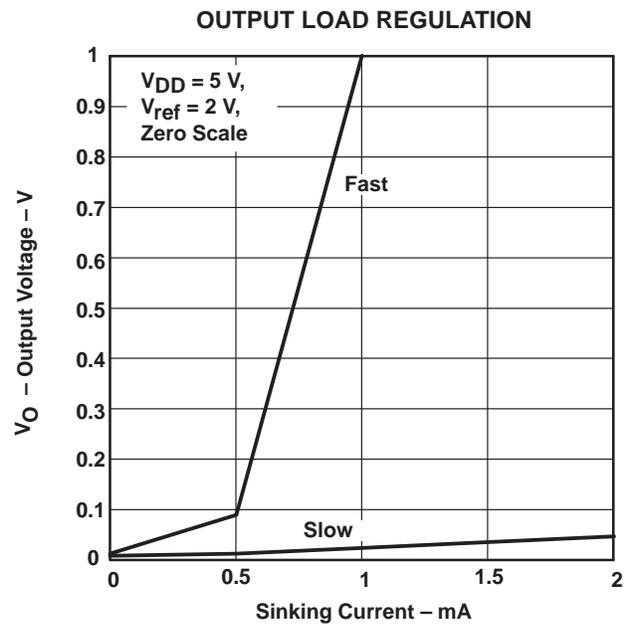


Figure 2

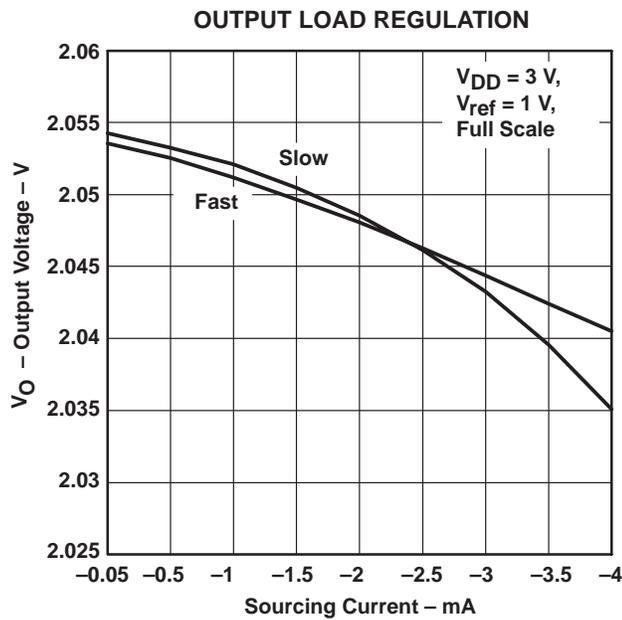


Figure 3

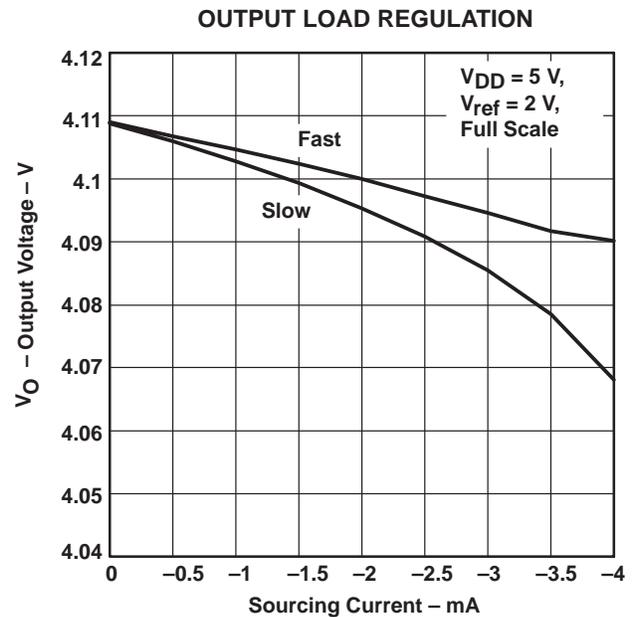


Figure 4



TYPICAL CHARACTERISTICS

TLV5630
INTEGRAL NONLINEARITY
vs
CODE

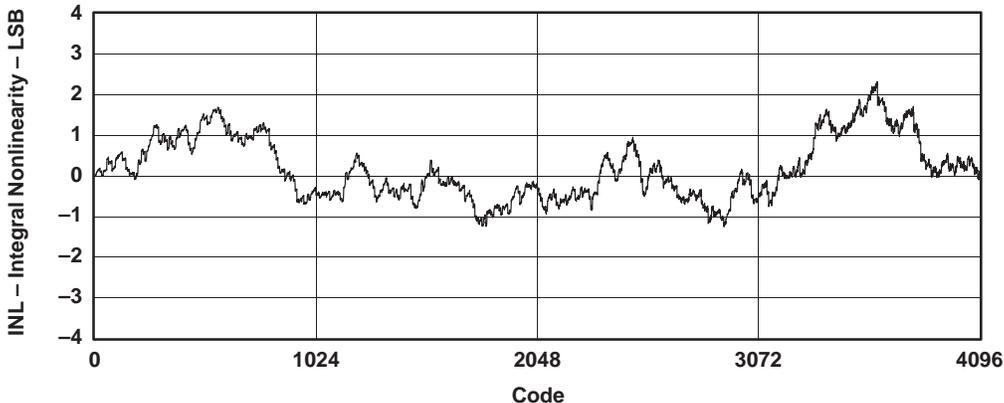


Figure 5

TLV5630
DIFFERENTIAL NONLINEARITY
vs
CODE

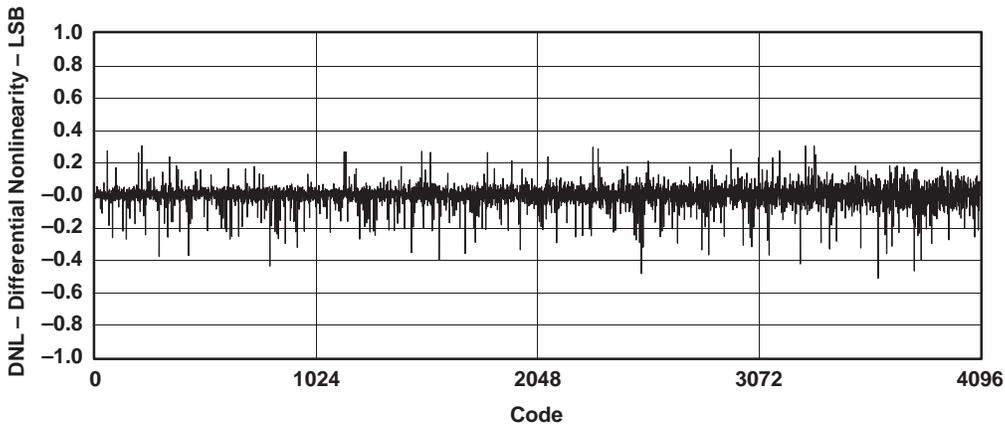


Figure 6

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TYPICAL CHARACTERISTICS

TLV5631
INTEGRAL NONLINEARITY
vs
CODE

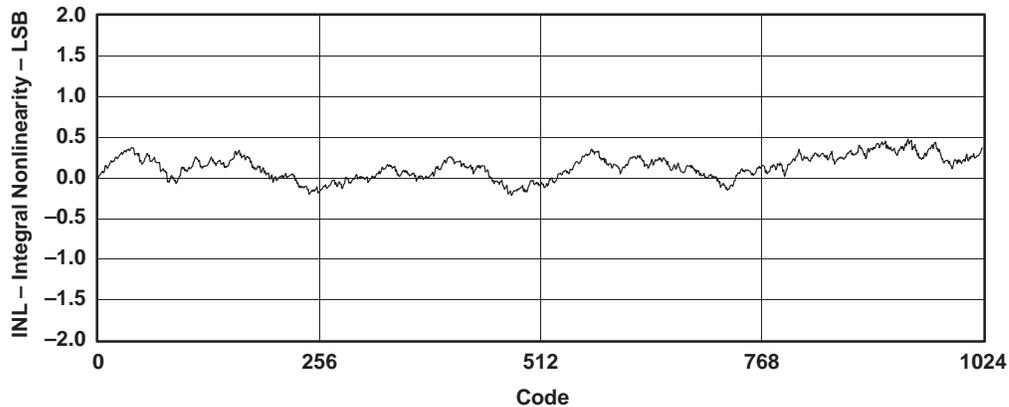


Figure 7

TLV5631
DIFFERENTIAL NONLINEARITY
vs
CODE

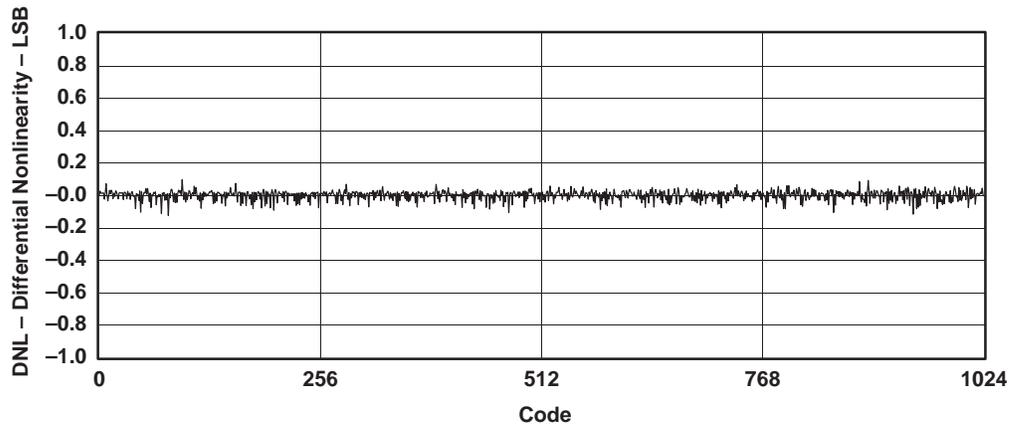


Figure 8



TYPICAL CHARACTERISTICS

TLV5632
INTEGRAL NONLINEARITY
VS
CODE

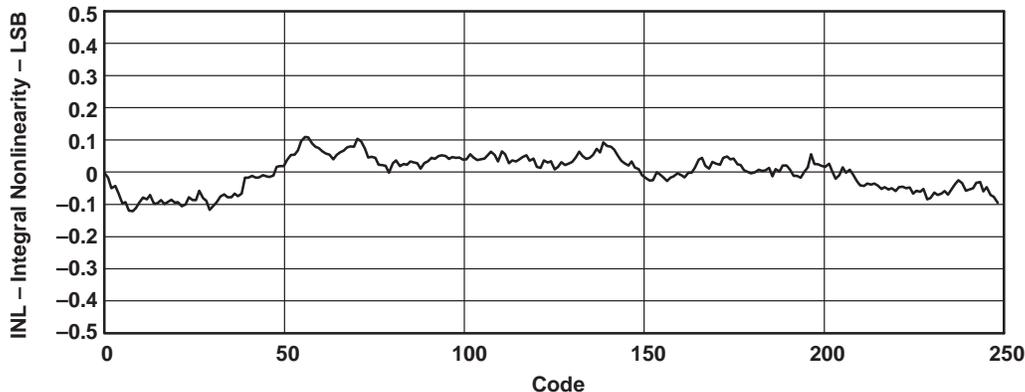


Figure 9

TLV5632
DIFFERENTIAL NONLINEARITY
VS
CODE

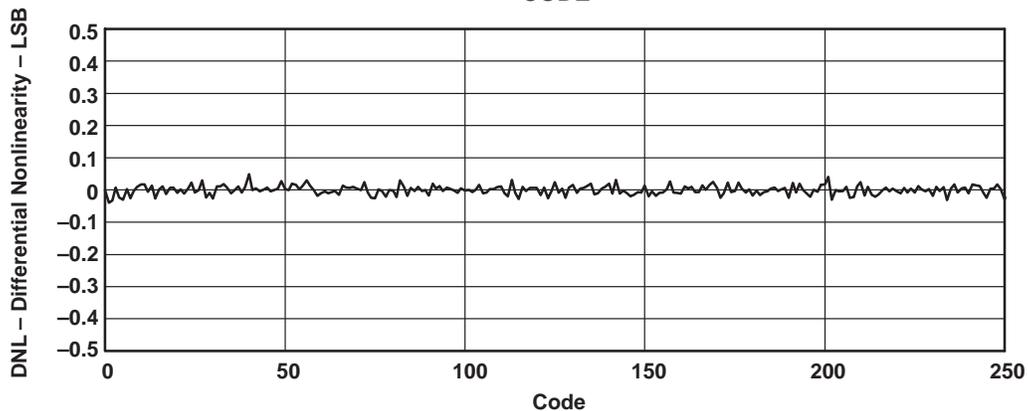
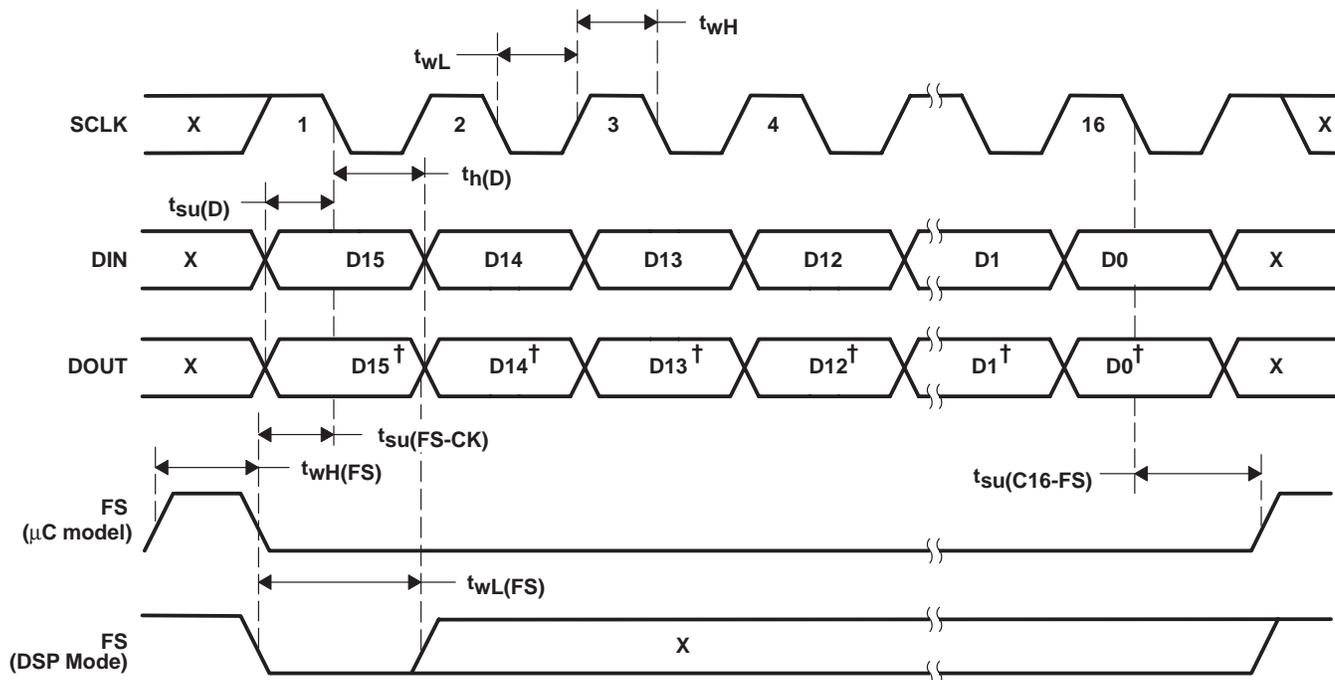


Figure 10

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PARAMETER MEASUREMENT INFORMATION



†Previous Input Data

Figure 11. Serial Interface Timing

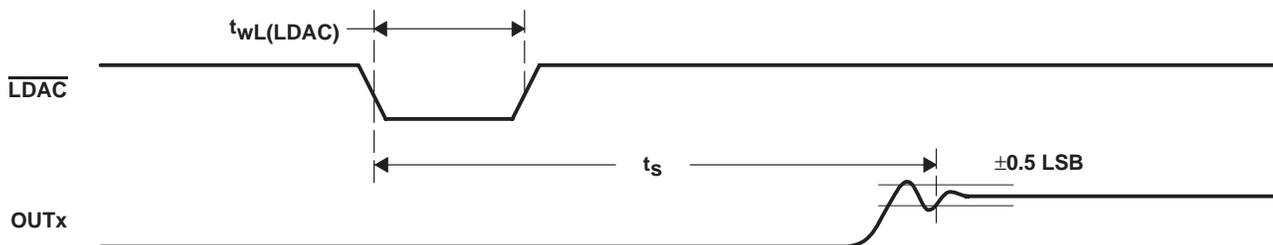


Figure 12. Output Timing

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APPLICATION INFORMATION

general function

The TLV5630/31/32 are 8-channel, single supply DACs, based on a resistor string architecture. They consist of a serial interface, a speed and power-down control logic, an internal reference, a resistor string, and a rail-to-rail output buffer.

The output voltage (full scale determined by reference) for each channel is given by:

$$2\text{REF} \frac{\text{CODE}}{0\text{x}1000} [\text{V}]$$

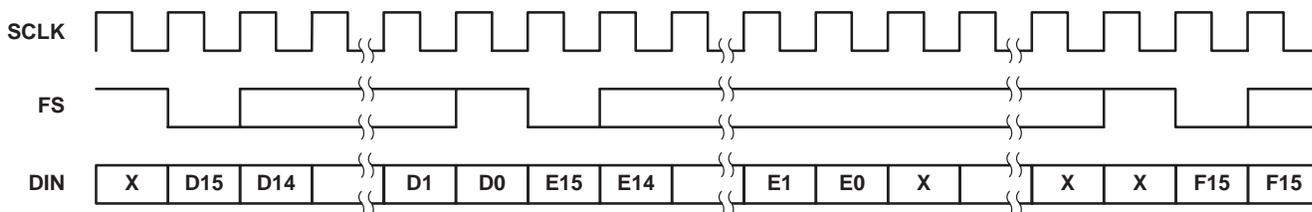
where REF is the reference voltage and CODE is the digital input value. The input range is 0x000 to 0xFFFF for the TLV5630, 0x000 to 0xFFC for the TLV5631, and 0x000 to 0xFF0 for the TLV5632. A power on reset initially puts the internal latches to a defined state (all bits zero).

serial interface

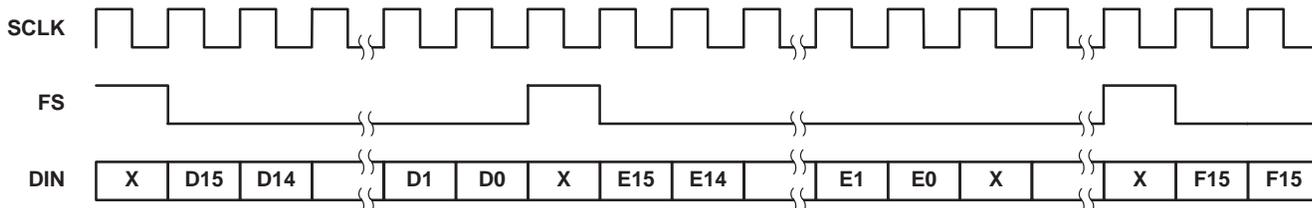
A falling edge of FS starts shifting the data on DIN starting with the MSB to the internal register on the falling edges of SCLK. After 16 bits have been transferred, the content of the shift register is moved to one of the DAC holding registers depending on the address bits within the data word. A logic 0 on the $\overline{\text{LDAC}}$ pin is required to transfer the content of the DAC holding register to the DAC latch and to update the DAC outputs. $\overline{\text{LDAC}}$ is an asynchronous input. It can be held low if a simultaneous update of all eight channels is not needed.

For daisy-chaining, DOUT provides the data sampled on DIN with a delay of 16 clock cycles.

DSP Mode:



μC Mode:



Difference between DSP mode (MODE = N.C. or 0) and uC (MODE = 1) mode:

- In μC mode FS needs to be held low until all 16 data bits have been transferred. If FS is driven high before the 16th falling clock edge the data transfer is cancelled. The DAC is updated after a rising edge on FS.
- In DSP mode FS only needs to stay low for 20 ns and can go high before the 16th falling clock edge.



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APPLICATION INFORMATION

serial clock frequency and update rate

The maximum serial clock frequency is given by:

$$f_{\text{sclkmax}} = \frac{1}{t_{\text{whmin}} + t_{\text{wlmin}}} = 30 \text{ MHz}$$

The maximum update rate is:

$$f_{\text{updatemax}} = \frac{1}{16 (t_{\text{whmin}} + t_{\text{wlmin}})} = 1.95 \text{ MHz}$$

Note, that the maximum update rate is just a theoretical value for the serial interface, as the settling time of the DAC has to be considered also.

data format

The 16 bit data word consists of two parts:

- Address bits (D15...D12)
- Data bits (D11...D0)

D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
A3	A2	A1	A0	Data											

Ax: Address bits. See table.

register map

A3	A2	A1	A0	FUNCTION
0	0	0	0	DAC A
0	0	0	1	DAC B
0	0	1	0	DAC C
0	0	1	1	DAC D
0	1	0	0	DAC E
0	1	0	1	DAC F
0	1	1	0	DAC G
0	1	1	1	DAC H
1	0	0	0	CTRL0
1	0	0	1	CTRL1
1	0	1	0	Preset
1	0	1	1	Reserved
1	1	0	0	DAC A and \bar{B}
1	1	0	1	DAC C and \bar{D}
1	1	1	0	DAC E and \bar{F}
1	1	1	1	DAC G and \bar{H}

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APPLICATION INFORMATION

DAC A–H and two-channel registers

Writing to DAC A–H sets the output voltage of channel A–H. It is possible to automatically generate the complement of one channel by writing to one of the four two-channel registers (DAC A and \bar{B} etc.).

The TLV5630 decodes all 12 data bits. The TLV5631 decodes D11 to D2 (D1 and D0 are ignored). The TLV5632 decodes D11 to D4 (D3 to D0 are ignored).

Preset

The outputs of all DAC channels can be driven to a predefined value stored in the Preset register by driving the \overline{PRE} input low. The \overline{PRE} input is asynchronous to the clock.

CTRL0

BIT	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
Function	X	X	X	X	X	X	X	PD	DO	R1	R0	IM
Default	X	X	X	X	X	X	X	0	0	0	0	0

PD : Full device power down 0 = normal 1 = power down
 DO : DOUT enable 0 = disabled 1 = enabled
 R1:0 : Reference select bits 0 = external, 1 = external, 2 = internal 1 V, 3 = internal 2 V
 IM : Input mode 0 = straight binary 1 = twos complement
 X : Reserved

If DOUT is enabled, the data input on DIN is output on DOUT with a 16 cycle delay. That makes it possible to daisy-chain multiple DACs on one serial bus.

CTRL1

BIT	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
Function	X	X	X	X	PGH	PEF	PCD	PAB	SGH	SEF	SCD	SAB
Default	X	X	X	X	0	0	0	0	0	0	0	0

P_{XY} : Power Down DAC_{XY} 0 = normal 1 = power down
 S_{XY} : Speed DAC_{XY} 0 = slow 1 = fast
 XY : DAC pair AB, CD, EF or GH

In power-down mode, the amplifiers of the selected DAC pair are disabled and the total power consumption of the device is significantly reduced. Power-down mode of a specific DAC pair can be selected by setting the P_{XY} bit within the data word to 1.

There are two settling time modes: fast and slow. Fast mode of a DAC pair is selected by setting S_{XY} to 1 and slow mode is selected by setting S_{XY} to 0.

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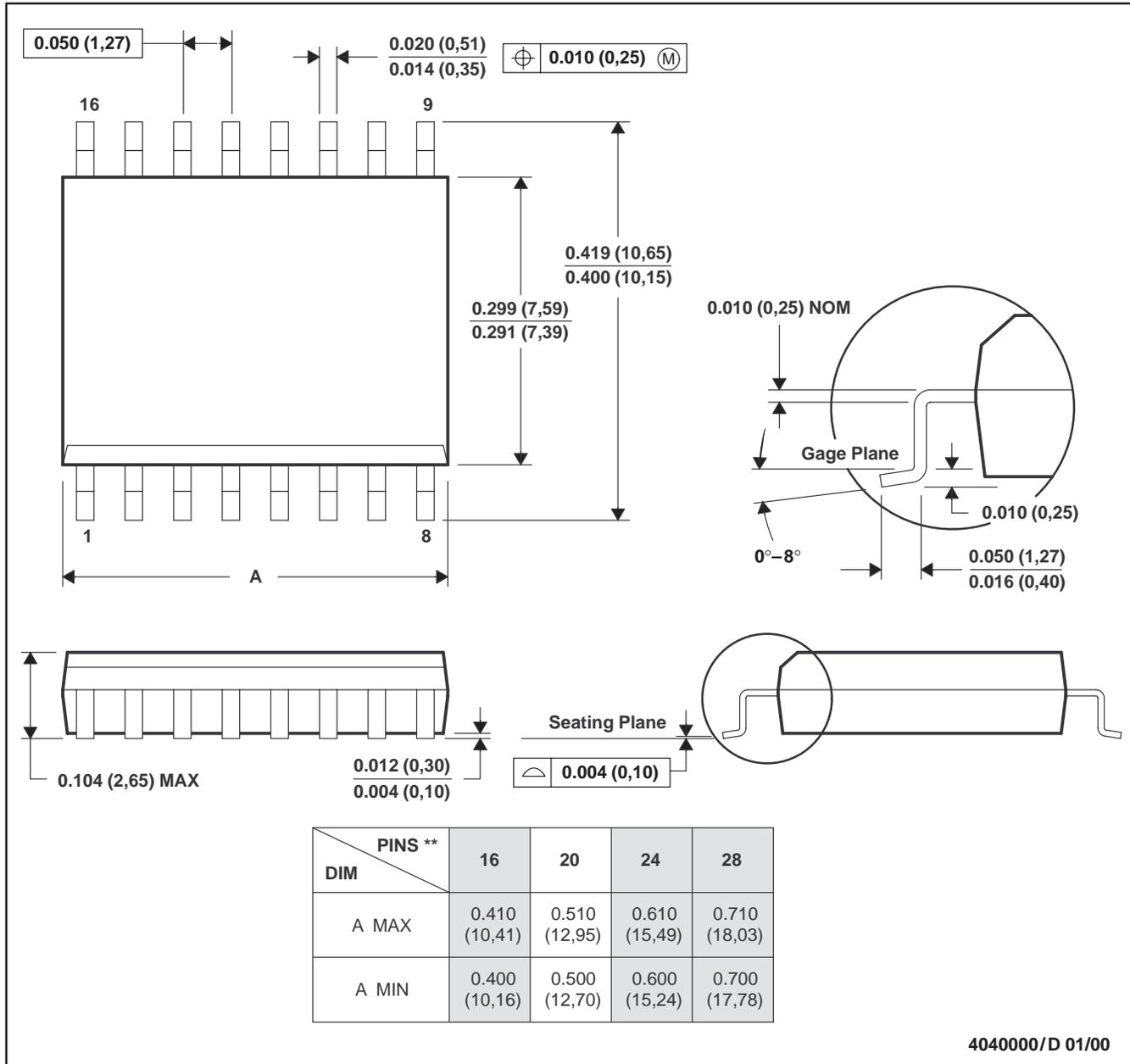
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MECHANICAL DATA

DW (R-PDSO-G)**

PLASTIC SMALL-OUTLINE PACKAGE

16 PINS SHOWN



- NOTES: A. All linear dimensions are in inches (millimeters).
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
 D. Falls within JEDEC MS-013

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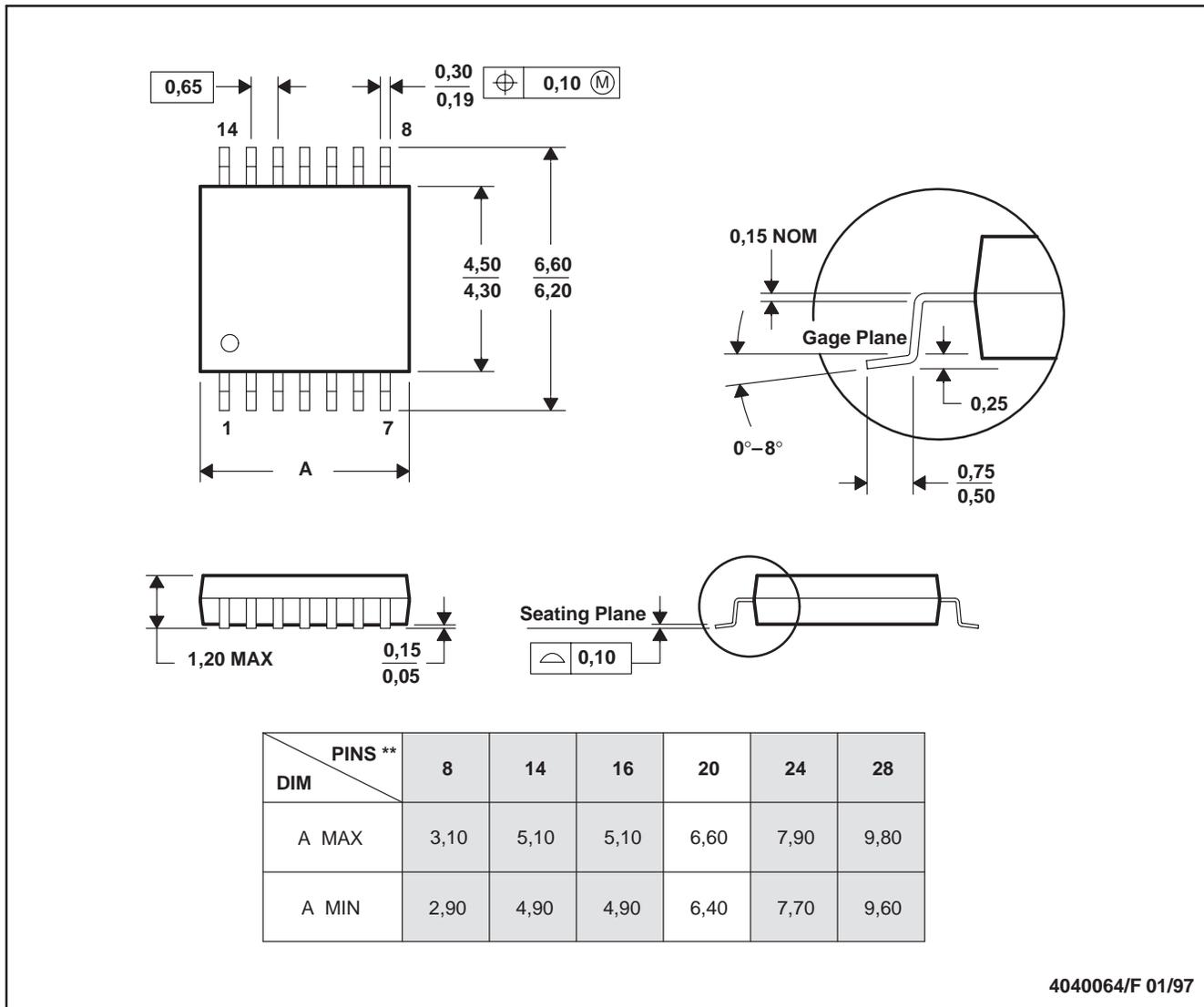
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MECHANICAL DATA

PW (R-PDSO-G)**

PLASTIC SMALL-OUTLINE PACKAGE

14 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
 D. Falls within JEDEC MO-153

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